

Title	Ferromagnetism induced by lattice volume expansion and amorphization in EuTiO ₃ thin films
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Citation	Journal of Materials Research (2013), 28(08): 1031-1041
Issue Date	2013-04
URL	http://hdl.handle.net/2433/173765
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Type	Journal Article
Textversion	author



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Journal:	Journal of Materials Research
Manuscript ID:	JMR-2012-0621.R2
Manuscript Type:	Invited Feature Paper
Date Submitted by the Author:	n/a
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Key Words:	ferromagnetic, oxide, thin film

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6 Ferromagnetism induced by lattice volume expansion and amorphization in EuTiO_3 thin
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Abstract

The lattice volume expansion or amorphization renders EuTiO_3 ferromagnetic although the stable phase of crystalline EuTiO_3 is an antiferromagnet. The lattice volume expansion is induced into crystalline EuTiO_3 thin film by utilizing the lattice mismatch between the thin film and a substrate. The magnetization at low temperatures monotonically increases with an increase in lattice volume for the crystalline EuTiO_3 thin film, coincident with the results of calculations based on hybrid Hartree-Fock density functional approach. The ferromagnetic interaction between Eu^{2+} ions is enhanced by the amorphization as well; amorphous EuTiO_3 thin film becomes a ferromagnet, and the Curie temperature is higher for amorphous Eu_2TiO_4 than for its crystalline counterpart. The phenomenon, that is, the volume expansion- and amorphization-induced ferromagnetism, is explained in terms of the competition between ferromagnetic and antiferromagnetic interactions among Eu^{2+} ions; the former stems from the indirect exchange interaction via Eu^{2+} 5d state and the latter is caused by the superexchange interaction via Ti^{4+} 3d state.

I. INTRODUCTION

Considerable attention has been paid to oxides containing transition metal elements for the last several decades from a point of view of their unique electronic structures and curious physical properties including electrical conduction, dielectric properties, magnetism, and optical properties. Among many sorts of oxide, those having perovskite and its related structures, in particular, exhibit intriguing electrical and magnetic properties. One of the prototypes of properties the oxides with perovskite structure manifest is ferroelectricity. Several kinds of oxide such as BaTiO_3 , $\text{Pb}(\text{Zr,Ti})\text{O}_3$, $(\text{Pb,L a})(\text{Zr,Ti})\text{O}_3$, and KNbO_3 are ferroelectric at room temperature, and they are practically utilized as capacitors, piezoelectric devices, surface acoustic wave (SAW) devices, and second-order nonlinear optical materials. Another interesting and important example of the properties can be found in so-called high- T_c superconductors. The copper oxide-based superconductors mainly discovered at the end of 80's such as $(\text{La,B a})_2\text{CuO}_4$, $\text{YBa}_2\text{Cu}_3\text{O}_7$, $\text{Bi}_2\text{Ca}_2\text{Sr}_2\text{Cu}_3\text{O}_{10}$, and so forth have perovskite-related structures. SrTiO_3 also crystallizes in a perovskite structure and becomes a superconductor when oxygen vacancy is introduced or dopants such as La^{3+} and Nb^{5+} are incorporated although its critical temperature is rather low; $T_c=0.1$ to 0.7 K depending on the concentration of defect or dopant.¹⁻⁴ For SrTiO_3 , recent study has revealed that two-dimensional electron gas is generated and leads to superconducting transition at 200 mK at an interface between SrTiO_3 and LaAlO_3 although both of the oxides are insulators.⁵ Also, two-dimensional electron gas confined in Nb-doped SrTiO_3 quantum well formed in between SrTiO_3 layers gives rise to a very large thermoelectric Seebeck coefficient.⁶ It is well-known that the SrTiO_3 itself shows quantum paraelectric behavior at low temperatures.

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6 As for magnetic properties of oxides with perovskite structure, compounds containing
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8 transition metal ion with mixed valence state, such as (La,Sr)MnO₃ and (La,Sr)CoO₃, show
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10 ferromagnetism at room temperature owing to the double exchange interaction between
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12 transition metal ions. These oxides are fairly rare examples of ferromagnetic oxides; most of
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14 the oxides are rather antiferromagnetic or ferrimagnetic below their magnetic transition
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16 temperature. Because the ferromagnetism observed in these oxides is closely associated with
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18 the conduction of charged carriers, the oxides, in particular manganese oxide-based compounds,
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20 have arrested a great deal of attention from a point of view of application to spintronics.
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22 Indeed, for the compounds such as (La,Ca)MnO₃, (La,Sr)MnO₃, (La,Ba)MnO₃, and
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24 (Pr,Ca)MnO₃, giant magnetoresistance (GMR) or colossal magnetoresistance (CMR) has been
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26 observed.⁷⁻¹² Furthermore, some of the oxides with perovskite-related structure are regarded as
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28 multiferroics, in which magnetically and dielectrically ordered states such as ferromagnetism
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30 and ferroelectricity coexist because of strong coupling between spin and phonon mode in the
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32 materials.^{13,14} For instance, BiMnO₃, which has a strained perovskite structure, shows
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34 ferromagnetic-paramagnetic phase transition at 105 K and at the same time, manifests
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36 ferroelectric-paraelectric transition at 750 to 770 K.¹⁵ Similar behavior was observed for
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38 BiFeO₃¹⁶ and TbMnO₃.¹⁷
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47 EuTiO₃ is also an oxide adopting perovskite structure and possessing interesting electrical
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49 and magnetic properties. Similarly to SrTiO₃, EuTiO₃ as a stable phase crystallizes in a cubic
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51 perovskite structure at room temperature and atmospheric pressure. The lattice constant of
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53 EuTiO₃ is 0.3905 nm at ambient temperature and pressure. This value is just the same as the
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55 lattice constant of SrTiO₃, as naturally expected from the similarity in ionic radii between Sr²⁺
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6 and Eu^{2+} . In addition, not only SrTiO_3 but EuTiO_3 exhibits quantum paraelectric behavior at
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8 low temperatures. On the other hand, magnetic moment due to $4f^7$ spins localized at the Eu^{2+}
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10 site brings about magnetic properties which are peculiar to EuTiO_3 but are absent in SrTiO_3 . It
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12 is known that the ensemble of magnetic moments of Eu^{2+} ions form a G-type antiferromagnetic
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14 ordering in EuTiO_3 below 5.3 K.^{18,19} Moreover, a strong coupling between spin and soft
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16 phonon mode exists in EuTiO_3 , as demonstrated by the experimental fact that not only magnetic
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18 susceptibility but dielectric constant manifests a drastic change at the Néel temperature, i.e.,
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20 $T_N=5.3$ K.²⁰ EuZrO_3 , which adopts an orthorhombic perovskite structure at room
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22 temperature^{21,22} and shows antiferromagnetic transition at 4.1 K,²² exhibits a similar
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24 magnetodielectric effect. The dielectric constant of EuZrO_3 is strongly dependent on an
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26 applied magnetic field below the Néel temperature.²³ These phenomena are of interest in
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28 relation to the multiferroics mentioned above.
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35 Recently, theoretical approaches have been carried out to dependence of magnetic and
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37 dielectric properties on a strain or a change in lattice volume for EuTiO_3 , and interesting results
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39 have been derived. Fennie and Rabe²⁴ predicted that both ferromagnetic and ferroelectric
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41 states are stabilized when a biaxial compressive stress is applied to induce a strain larger than
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43 1.2 % in the plane parallel to the surface of EuTiO_3 thin film although the stable phase of
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45 EuTiO_3 is antiferromagnetic and quantum paraelectric at low temperatures as described above.
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47 In their calculations, the biaxial compressive strain is introduced in the surface of thin film
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49 while the lattice volume is kept constant, so that the lattice is elongated in a direction
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51 perpendicular to the film surface. Ranjan et al.²⁵ performed theoretical calculations based on
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53 LDA (local density approximation) + U approach and found that ferromagnetic state becomes
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6 more stable than G-type antiferromagnetic state as either the lattice volume of EuTiO_3 or the
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8 on-site Coulomb repulsion U for a 4f electron of Eu^{2+} ion is increased. Akamatsu et al.²⁶
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10 carried out hybrid Hartree-Fock density functional calculations and revealed that as the lattice
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12 volume of EuTiO_3 is isotropically increased, the exchange coupling constant between
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14 nearest-neighboring Eu^{2+} ions increases and changes its sign from negative to positive above a
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16 critical value of lattice volume. This means that the increase in lattice volume leads to the
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18 stabilization of ferromagnetic phase in EuTiO_3 . The result deduced by Akamatsu et al. is
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20 described below in detail.
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25 On the other hand, experimental approaches have been also performed to the relation
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27 between a strain or a lattice volume and magnetic as well as dielectric properties of EuTiO_3 .
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29 Fujita et al.²⁷ found that as-deposited EuTiO_3 thin film on SrTiO_3 (001) substrate has a lattice
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31 constant elongated by 2.4 % in a direction perpendicular to the film surface and behaves as a
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33 ferromagnet at low temperatures, whereas post-annealed EuTiO_3 possesses a lattice constant just
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35 the same as those of bulk EuTiO_3 as well as SrTiO_3 substrate and shows antiferromagnetic
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37 transition at 5.1 K, as expected for the stable phase of EuTiO_3 . This fact suggests that the
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39 ferromagnetic behavior is brought about by the increase in lattice volume observed for the
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41 as-deposited EuTiO_3 thin film, as theoretically predicted for the relation between magnetic
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43 structure and lattice volume of EuTiO_3 . By following the theoretical calculations performed
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45 by Fennie and Rabe,²⁴ Lee et al.²⁸ carried out spin-polarized GGA (generalized gradient
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47 approximation) + U approach to the EuTiO_3 thin film, and clarified that tensile as well as
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49 compressive strain gives rise to the stabilization of ferromagnetic and ferroelectric phase of
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60 EuTiO_3 . They also experimentally demonstrated that EuTiO_3 thin film under tensile strain

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6 caused by DyScO₃ substrate becomes a ferroelectric ferromagnet due to the strong spin-lattice
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8 coupling. They observed that the intensity of second-harmonic wave generated in the EuTiO₃
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10 thin film on DyScO₃ substrate gradually increases with a decrease in temperature below about
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12 250 K. This phenomenon was related to the fact that the ferroelectric state is stabilized below
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14 this temperature.
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18 The above-mentioned theoretical and experimental results seem to indicate that there
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20 exists a correlation between the strain or the lattice volume and magnetic structure of EuTiO₃,
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22 but experimental study on the effect of a systematic variation in lattice volume on the magnetic
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24 properties of EuTiO₃ has not been performed. In the present investigation, we achieve a
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26 systematic variation in lattice volume of EuTiO₃ thin film by changing the type of substrate
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28 compound so that the lattice mismatch between the thin film and the substrate leads to a strain
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30 in the plane parallel to the film surface. For the growth of thin films, a pulsed laser deposition
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32 method is utilized. We demonstrate that magnetization at low temperatures correlates with the
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34 lattice volume of EuTiO₃ thin film; the experimental result qualitatively supports the theoretical
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36 prediction. On the other hand, when a SiO₂ glass plate is used as a substrate and it is kept at
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38 room temperature during the deposition process, amorphous EuTiO₃ thin film is obtained.
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40 Interestingly, the amorphous EuTiO₃ thin film is ferromagnetic at low temperatures and the
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42 Curie temperature of the amorphous phase is comparable to the Néel temperature of the
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44 crystalline EuTiO₃. Amorphous Eu₂TiO₄ thin film also exhibits ferromagnetic transition, and
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46 the Curie temperature is higher than that of its crystalline counterpart.²⁹ These are very rare
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48 phenomena; amorphous oxides exhibiting ferromagnetic transition have been never found thus
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50 far, and the magnetic phase transition temperature is usually lower by one order of magnitude
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6 for amorphous oxide than for its crystalline counterpart with the identical composition. In this
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8 paper, we report on these fairly interesting phenomena.
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10 11 12 13 II. EXPERIMENTAL

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17 A pulsed laser deposition (PLD) method was carried out for the synthesis of crystalline
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19 EuTiO_3 thin films. $\text{Eu}_2\text{Ti}_2\text{O}_7$, the structure of which is pyrochlore, was used as a target
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21 material. A sintered body of $\text{Eu}_2\text{Ti}_2\text{O}_7$ was prepared via conventional solid-state reaction
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23 between Eu_2O_3 and TiO_2 . The EuTiO_3 thin films were grown on (001) plane of
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25 single-crystalline LaAlO_3 , SrTiO_3 , and DyScO_3 , having the perovskite structure similarly to
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27 EuTiO_3 , as a substrate, so that the different lattice constant among the substrate compounds
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29 could give rise to the difference in lattice volume among EuTiO_3 thin films deposited on the
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31 substrates. The lattice constant of EuTiO_3 , LaAlO_3 , SrTiO_3 , and DyScO_3 is 0.3905, 0.3790,
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33 0.3905, and 0.3944 nm, respectively. Hence, considering the lattice mismatch between the
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35 EuTiO_3 thin film and the substrate compounds, shrinkage and elongation of lattice in the plane
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37 parallel to the surface of the EuTiO_3 thin film were anticipated for LaAlO_3 and DyScO_3
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39 substrates, respectively, and neither shrinkage nor elongation was expected for SrTiO_3 substrate.
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47 The target material was irradiated with a pulsed KrF excimer laser operating at a power of 180
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49 mJ, a wavelength of 248 nm, and a repetition rate of 5 Hz. The substrate was set 2.5 cm apart
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51 from the target and kept at 650°C. The deposition was performed under an oxygen partial
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53 pressure of 1.0×10^{-5} Pa.
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57 Amorphous thin films with nominal compositions of EuTiO_3 and Eu_2TiO_4 were also
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6 prepared by using the PLD method. Polycrystalline EuTiO_3 was utilized as a target material
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8 for the amorphous EuTiO_3 thin film. The target material was synthesized via conventional
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10 solid-state reaction. Reagent-grade Eu_2O_3 and TiO_2 were weighed so that the prescribed
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12 composition was obtained and mixed thoroughly. The mixture was pressed into a pellet, and
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14 the pellet was sintered at 1400°C for 12 h in air. The resultant material was pulverized, mixed
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16 thoroughly, and pressed into a pellet. The pellet was sintered at 1200°C for 24 h in a reducing
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18 atmosphere of 95 vol% Ar and 5 vol% H_2 . The process of pulverizing and sintering in the
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20 reducing atmosphere was repeated four times. The sintered body thus obtained was used as
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22 the target. On the other hand, as for the target material to prepare amorphous Eu_2TiO_4 ,
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24 reagent-grade Eu_2O_3 was first reduced into EuO by mixing Eu_2O_3 powder with slightly excess
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26 amount of graphite powder, making a pellet, and sintering at 1450°C for 6 h in a graphite
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28 crucible under the reducing atmosphere. A sintered body of EuO thus obtained was pulverized
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30 and mixed thoroughly with TiO_2 powder to reach the prescribed composition. The mixture
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32 was sintered at 1500°C for 10 h in a graphite crucible under the reducing atmosphere. The
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34 resultant material was used as a target for the preparation of amorphous Eu_2TiO_4 thin film.
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36 The target material was set 2.5 cm away from SiO_2 glass substrate. The deposition of thin
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38 films was performed by irradiating the target with a KrF excimer laser operating at a
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40 wavelength of 248 nm, a repetition rate of 10 Hz, and a fluence of 2 to $3 \text{ mJ}/\text{cm}^2$. The
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42 substrate was kept in a vacuum chamber with a base pressure of 10^{-6} Pa, and was not
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44 intentionally heated.
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6 Rutherford backscattering spectrometry was carried out using a 2.0 MeV He^{2+} to estimate
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8 the composition and thickness of the resultant thin films. Atomic force microscopy (AFM)
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10 was performed to observe the surface morphology of the thin films from a point of view of
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12 atomistic level. X-ray diffraction (XRD) with $\text{CuK}\alpha$ radiation was utilized to identify
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14 crystalline phases and to evaluate the lattice constant for crystalline EuTiO_3 thin films deposited
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16 on several kinds of substrate. XRD measurements were also carried out to confirm that no
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18 crystalline phases were present in the amorphous thin films. For the crystalline EuTiO_3 thin
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20 films, X-ray reciprocal space mappings were obtained by using a four-circle XRD apparatus.
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22 High-resolution transmission electron microscopy (HRTEM), selected area electron diffraction
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24 (SAED), and X-ray absorption spectroscopy were also performed for the amorphous thin films.
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26 The extended X-ray absorption fine structure (EXAFS) spectra were obtained for Eu L_3 -edge to
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28 examine the local structure of Eu ion in the amorphous thin films. Details of the procedure of
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30 measurement and analysis of EXAFS were described elsewhere.³⁰ Variation of magnetization
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32 with temperature and magnetic field was measured by using a superconducting quantum
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34 interference device (SQUID).
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44 III. RESULTS AND DISCUSSION

45 Lattice volume expansion-induced ferromagnetism of EuTiO_3 thin film

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49 The molar ratio of Eu to Ti, estimated by the Rutherford backscattering, in the thin films
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51 deposited on LaAlO_3 , SrTiO_3 , and DyScO_3 substrates is shown in Table 1. The experimental
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53 error in the molar ratio was evaluated to be 0.15 to 0.70 %. The molar ratio of Eu to Ti is
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55 almost equal to 1 for all the thin films, indicating that the as-deposited thin films are
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6 stoichiometric as far as the molar ratio of cations is concerned. Also, it was demonstrated by
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8 the out-of-plane and in-plane XRD measurements that the thin films are composed of single
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10 phase of EuTiO_3 (although the XRD patterns are not shown here). The data obtained from the
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12 XRD measurements, i.e., the reciprocal space mappings are discussed below in detail. Figure
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14 1 illustrates the AFM image for the EuTiO_3 thin films on the different types of substrate. LAO,
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16 STO, and DSO indicated in the figure denote the LaAlO_3 , SrTiO_3 , and DyScO_3 substrates,
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18 respectively. So-called stepped and terraced structure is observed, suggesting that the surface
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20 of the thin films is atomically flat and smooth.
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25 Figure 2 depicts the reciprocal space mappings for EuTiO_3 thin films deposited on
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27 LaAlO_3 , SrTiO_3 , and DyScO_3 substrates. Q_x and Q_y stand for the reciprocal lattice vectors
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29 corresponding to the lattice vector parallel and perpendicular to the film surface, respectively.
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31 Bragg spots ascribed to the thin film and the substrate are observed in each of the reciprocal
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33 space mappings. The small circle shown in each of the illustrations denotes the reciprocal
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35 lattice for bulk EuTiO_3 . It is possible to evaluate a strain or a change in lattice volume for
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37 EuTiO_3 thin film by comparing the reciprocal lattice of the thin film with that of bulk EuTiO_3 .
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39 In the case that LaAlO_3 is used as a substrate, Q_y of EuTiO_3 thin film is much smaller than that
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41 of bulk EuTiO_3 , whereas Q_x is slightly larger for EuTiO_3 thin film than for bulk EuTiO_3 . This
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43 fact indicates that the lattice of the EuTiO_3 thin film is elongated in a direction perpendicular to
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45 the surface of the thin film and slightly shrinks in a direction parallel to the surface. In this
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47 case, the lattice of EuTiO_3 thin film is elongated by +1.89 % in a direction perpendicular to the
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49 surface and shrinks by -0.3 % in the plane parallel to the surface, respectively. Therefore, the
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51 change in lattice volume from the bulk EuTiO_3 is evaluated to be +1.56 %. Similar estimation
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6 of variation in lattice constant can be performed for the SrTiO_3 and DyScO_3 substrates. The
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8 results are summarized in Table 2, where Δl_1 and Δl_2 denote the variation in lattice constant in a
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10 direction parallel and perpendicular to the surface of the thin film, respectively, and ΔV stands
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12 for the change in lattice volume for the EuTiO_3 thin films. As expected from the degree of
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14 lattice mismatch, the lattice volume of EuTiO_3 thin film is the largest for the DyScO_3 substrate
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16 and the smallest for the LaAlO_3 substrate. For the SrTiO_3 substrate, an intermediate value is
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19 obtained.

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23 Whereas the in-plane lattice constant of EuTiO_3 thin film is varied by altering the kind of
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25 substrate compound, the out-of-plane lattice constant of EuTiO_3 thin film is elongated when
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27 compared to the bulk EuTiO_3 irrespective of the sort of substrate compound. As a result, the
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29 lattice volume of EuTiO_3 thin film becomes larger than that of bulk EuTiO_3 even when LaAlO_3 ,
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31 whose lattice constant is smaller than that of bulk EuTiO_3 , is used as a substrate. In general,
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33 when the lattice constant is larger for material of thin film than for substrate material, the
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35 in-plane lattice constant of the thin film becomes shorter, and the out-of-plane lattice constant
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37 becomes longer because of the compressive strain at the interface between the thin film and the
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39 substrate.^{28,31} For instance, the out-of-plane lattice constant of EuTiO_3 thin film deposited on
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(LaAlO_3)_{0.3}($\text{Sr}_2\text{AlTaO}_6$)_{0.7} (LSAT) substrate, the lattice constant of which is smaller than that of
bulk EuTiO_3 , becomes longer by about 0.89 %.³¹ Compared to this value, however, the
elongation of the lattice in the out-of-plane direction is more significant for the present EuTiO_3
thin film deposited on LaAlO_3 substrate (see Table 2). Moreover, such elongation of lattice in
the out-of-plane direction of EuTiO_3 thin film takes place even for the DyScO_3 substrate whose
lattice constant is larger than that of bulk EuTiO_3 , as shown in Table 2. One possible origin of

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6 the large elongation of lattice in a direction perpendicular to the surface of the present EuTiO_3
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8 thin films is that single atomic layers such as EuO and TiO_2 layers may be inserted into the
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10 perovskite structure during the deposition process to form a compound like the
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12 Ruddlesden-Popper phase. However, this possibility can be ruled out, considering the fact that
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14 post-annealing of as-deposited EuTiO_3 thin film grown on SrTiO_3 substrate makes the lattice
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16 constant shrink to be just the same as the lattice constant of bulk EuTiO_3 .²⁷ Some
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18 oxygen-related point defects may cause the phenomenon, although experimental evidence is
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20 absent at this moment, and hence, further study is needed to solve the problem.
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26 Magnetic properties are shown in Figs. 3 and 4 for the EuTiO_3 thin films deposited on
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28 LaAlO_3 , SrTiO_3 , and DyScO_3 substrates. Figure 3 depicts the temperature dependence of
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30 magnetization measured at an applied magnetic field of 100 Oe for EuTiO_3 thin films grown on
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32 LaAlO_3 (denoted by diamond), SrTiO_3 (circle), and DyScO_3 (square) substrates as well as for
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34 bulk EuTiO_3 (triangle). The inset of the figure is a magnified view of the magnetization data
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36 for bulk EuTiO_3 . It is seen that the bulk EuTiO_3 manifests an antiferromagnetic transition at
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38 about 5 K, as reported in literature.^{18,19} In contrast, different behavior is observed for the
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40 EuTiO_3 thin films; the magnetization drastically increases below about 5 K as the temperature is
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42 decreased for all the EuTiO_3 thin films. Figure 4 illustrates the variation of magnetization with
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44 magnetic field at 2 K for EuTiO_3 thin films grown on LaAlO_3 (denoted by diamond), SrTiO_3
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46 (circle), and DyScO_3 (square) substrates as well as for bulk EuTiO_3 (triangle). The insets show
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48 the magnetization at low magnetic fields for EuTiO_3 thin film grown on SrTiO_3 substrate (right
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50 inset: circle) and for bulk EuTiO_3 (left inset: triangle). It is obvious that the magnetic field
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52 dependence of magnetization is different between the EuTiO_3 thin film and the bulk EuTiO_3 ; the
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EuTiO₃ thin film grown on SrTiO₃ substrate manifests magnetic field dependence of magnetization peculiar to a ferromagnet, whereas a spin-flip transition characteristic of an antiferromagnet is clearly observed for the bulk EuTiO₃. The ferromagnetic behavior is seen for the EuTiO₃ thin films grown on LaAlO₃ and DyScO₃ substrates as well. The results are in good agreement with the temperature dependence of magnetization illustrated in Fig. 3. It is also found in Fig. 4 that the saturation magnetization for the EuTiO₃ thin films is $6.4\mu_B$ to $6.8\mu_B$, where μ_B is the Bohr magneton. These values are almost identical to the theoretical magnetic moment of Eu²⁺, i.e., $7\mu_B$, suggesting that almost all the europium ions are present as a divalent state in the thin films. The fact that the valence state of almost all the europium ions in the thin films is +2 was confirmed by conversion electron ¹⁵¹Eu Mössbauer spectroscopy.²⁷ For instance, the fraction of Eu²⁺ in the total number of europium ion is 96 and 98 % for as-deposited and annealed EuTiO₃ thin films grown on SrTiO₃ substrate, respectively. The fraction of Eu²⁺ and Eu³⁺ in EuTiO₃, or strictly speaking, the composition of which is EuTiO_{3- δ} , is very important because it may affect the magnetic properties. An increase in the fraction of Eu³⁺ possibly raises the concentration of conduction electron, leading to the ferromagnetic order of Eu²⁺ ions through the mechanism of magnetic polaron or Ruderman-Kittel-Kasuya-Yoshida (RKKY) interaction. The fact that the fraction of Eu³⁺ is fairly small in the preset EuTiO₃ thin films rules out the possibility of these mechanisms for the ferromagnetism observed in the present thin films. This is further supported by the fact that the evident antiferromagnetic transition occurs in the annealed EuTiO₃ thin film whereas the ferromagnetism is observed in the as-deposited EuTiO₃ thin film although the fraction of Eu³⁺ in the annealed EuTiO₃ thin film is almost the same as that in the as-deposited EuTiO₃ thin film.²⁷

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6 A look at magnetization shown in Fig. 3 reveals that the low-temperature magnetization is
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8 the highest for DyScO₃ substrate, intermediate for SrTiO₃, and the lowest for LaAlO₃ substrate.
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10 Considering the above-mentioned experimental fact that the lattice volume of EuTiO₃ thin film
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12 depends on the sort of substrate compound and increases in the order that DyScO₃ > SrTiO₃ >
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14 LaAlO₃, it seems that the low-temperature magnetization monotonically increases with an
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16 increase in the lattice volume of EuTiO₃ thin film. This tendency is coincident with the result
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18 derived by theoretical approaches.^{25,26} Akamatsu et al.²⁶ calculated energy for different spin
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20 configurations in EuTiO₃ as shown in Fig. 5 by using the hybrid Hartree-Fock density
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22 functional approach. When a prototype of spin-Hamiltonian for Heisenberg system
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$$25 \quad H_{\text{spin}} = -2 \sum_{i>j} J_{ij} \mathbf{S}_i \cdot \mathbf{S}_j \quad (1)$$

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27 is assumed, the energy of spin system is expressed by

$$28 \quad E_F = E_0 + 2S(S+1)(-12J_1 - 24J_2), \quad (2)$$

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30 and

$$31 \quad E_G = E_0 + 2S(S+1)(12J_1 - 24J_2), \quad (3)$$

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33 for ferromagnetic and G-type antiferromagnetic spin configurations in EuTiO₃ lattice,
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35 respectively. Here, J₁ and J₂ stand for the exchange coupling constant for the
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37 nearest-neighbor and the next-nearest-neighbor Eu²⁺ ions, respectively (see Fig. 5).
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39 Equations (2) and (3) indicate that the difference in energy between ferromagnetic and G-type
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41 antiferromagnetic states depends only on the sign of J₁. In other words, whether the
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43 ferromagnetic or G-type antiferromagnetic state is stable for 4f spins in EuTiO₃ is determined
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45 only by the exchange interaction among the nearest-neighbor Eu²⁺ ions. The hybrid
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6 Hartree-Fock density functional approach indicates that the exchange coupling constant J_1
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8 monotonically increases as the lattice volume of EuTiO_3 increases and that J_1 changes its sign
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10 from negative to positive when an increase in lattice volume of EuTiO_3 exceeds about 5 %.²⁶
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12 Subsequently, the ferromagnetic state becomes more stable than the G-type antiferromagnetic
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14 state when the lattice volume is increased beyond this critical value. The result derived from
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16 the calculations that J_1 is positive and monotonically increases with an increase in the lattice
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18 volume above the critical value is qualitatively coincident with the present experimental result
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20 shown in Fig. 3 and Table 2.
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25 The calculations by Akamatsu et al. also suggest that the overlap between the 4f orbital of
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27 Eu^{2+} and the 3d orbital of Ti^{4+} in the EuTiO_3 lattice becomes more significant as the lattice
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29 volume is decreased.²⁶ It should be noted that an overlap between the Eu 4f and the O 2p
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31 orbitals does not take place even when the lattice volume is decreased. The overlap between
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33 the 4f orbital of Eu^{2+} and the 3d orbital of Ti^{4+} can bring about the superexchange interaction
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35 between the nearest-neighboring Eu^{2+} ions, leading to antiferromagnetic configuration of
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37 magnetic moments of Eu^{2+} ions. This idea stems from the fact that the Eu 4f orbital is
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39 non-orthogonal to the Ti 3d orbital. According to Anderson's theory of superexchange
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41 interaction,³² antiferromagnetic coupling is stabilized by the overlap between magnetic orbitals
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43 through intervening orbital, such as p state of non-magnetic anion, which is non-orthogonal to
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45 the magnetic orbital. Hence, the superexchange interaction between Eu^{2+} ions via the Ti 3d
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47 states is expected to be antiferromagnetic. On the other hand, the indirect exchange coupling
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49 between 4f spins via 5d state of Eu^{2+} gives rise to ferromagnetic interaction between the
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51 nearest-neighboring Eu^{2+} ions.^{19,33-35} The mechanism to bring about the ferromagnetic
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6 interaction is schematically illustrated in Fig. 6. The indirect exchange interaction is such a
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8 process that an electron excited from the 4f level into the vacant 5d level of an Eu^{2+} ion is
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10 transferred to the 5d level of the nearest-neighbor Eu^{2+} ion and interacts with 4f spins at the
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12 Eu^{2+} ion so that the spins in 5d and 4f states are parallel. These antiferromagnetic and
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14 ferromagnetic interactions compete with each other. The superexchange interaction via 3d
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16 state of Ti^{4+} becomes weaker as the lattice volume of EuTiO_3 is increased, because of the less
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18 overlapping between 4f orbital of Eu^{2+} and 3d orbital of Ti^{4+} . At the same time, the indirect
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20 exchange coupling between 4f spins via 5d state of Eu^{2+} to bring about ferromagnetic
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22 configuration becomes weaker as the lattice volume of EuTiO_3 is increased, because the
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24 separation between the nearest-neighbor Eu^{2+} ions becomes longer as the lattice volume is
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26 increased.^{34,35} In EuTiO_3 , the superexchange interaction via Ti^{4+} 3d state becomes less
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28 dominant than the indirect exchange coupling via Eu^{2+} 5d state as the lattice volume becomes
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30 larger. Consequently, ferromagnetic phase is stabilized in EuTiO_3 with expanded lattice
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32 volume.
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42 Ferromagnetism of amorphous EuTiO_3 and Eu_2TiO_4 thin films

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44 An attempt was made to synthesize amorphous EuTiO_3 and Eu_2TiO_4 thin films on SiO_2
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46 glass substrate by using the PLD method. According to the RBS measurements, the molar
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48 ratio of Eu to Ti is estimated to be 1.00:1.00 and 2.00:1.06 for thin films prepared from the
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50 target materials with EuTiO_3 and Eu_2TiO_4 compositions, respectively; the molar ratio for the
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52 thin films is almost identical to that for the target materials. Figure 7 shows the XRD patterns
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54 for EuTiO_3 and Eu_2TiO_4 thin films as well as HRTEM image and SAED pattern for EuTiO_3 .
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6 In the figure, a-ETO and a-2ETO stand for the thin films with EuTiO_3 and Eu_2TiO_4
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8 compositions, respectively. No sharp diffraction lines ascribable to crystalline phases but halo
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10 patterns peculiar to amorphous structure are observed in the XRD diagrams, suggesting that the
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12 thin films are amorphous and include no crystalline phases. The halo patterns at around $2\theta =$
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14 30° and 20° are attributable to the thin film and SiO_2 glass substrate, respectively. The
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16 HRTEM image and the SAED pattern also indicate that the EuTiO_3 thin film contains no
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18 crystalline phases, confirming that the thin film is amorphous. Similar results were derived for
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20 the Eu_2TiO_4 thin film from its HRTEM image and SAED pattern.
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25 Figure 8 illustrates the variation of magnetization with temperature measured at an
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27 applied dc magnetic field of 100 Oe for the amorphous EuTiO_3 and Eu_2TiO_4 thin films. The
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29 magnetization is very low at high temperatures; the temperature dependence of magnetic
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31 susceptibility at high temperatures is describable in terms of the Curie-Weiss law:
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$$\chi = \frac{NM_B^2 \mu_B^2}{3k_B(T - \theta_W)} \quad (4)$$

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38 where χ is the magnetic susceptibility, T is the temperature, N is the number density of magnetic
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40 moment, μ_B is the Bohr magneton, M_B is the effective number of Bohr magnetons, k_B is the
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42 Boltzmann constant, and θ_W is the Weiss temperature. On the other hand, as the temperature is
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44 decreased, the magnetization increases drastically below a certain temperature. The behavior
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46 indicates that the thin films are ferromagnetic at low temperatures. The Curie temperature
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48 estimated as an inflection point (as indicated by an arrow in Fig. 8) in the magnetization as a
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50 function of temperature is $T_C = 5.5$ K and 14 K for the amorphous EuTiO_3 and Eu_2TiO_4 ,
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53 respectively. First of all, it is surprising that amorphous EuTiO_3 exhibits ferromagnetic phase
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6 transition although the stable phase of crystalline EuTiO_3 is a G-type antiferromagnet as
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8 mentioned above. Besides, the Curie temperature, i.e., 5.5 K is comparable to the Néel
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10 temperature of the crystalline counterpart, i.e., 5.3 K. Secondly, the ferromagnetic phase
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12 transition is observed for the amorphous Eu_2TiO_4 thin film as well as crystalline phase of
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14 Eu_2TiO_4 , and moreover, the Curie temperature of the amorphous phase, i.e., $T_C=14$ K is rather
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16 higher than that of crystalline counterpart, i.e., $T_C=9$ K.³⁶ The Weiss temperature derived from
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18 the fit of Eq. (4) to the magnetic susceptibility data at high temperatures is $\theta_W=+8.0$ and $+17.6$
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20 K for the amorphous EuTiO_3 and Eu_2TiO_4 , respectively.²⁹ These values are significantly
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22 higher than the Weiss temperature of their crystalline counterparts, i.e., $\theta_W=+3.8$ K¹⁹ and $+10$
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24 K³⁵ for crystalline EuTiO_3 and Eu_2TiO_4 , respectively, clearly indicating that the amorphization
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26 enhances the ferromagnetic interaction among Eu^{2+} ions. Considering the effect of
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28 amorphization on the magnetic properties for other transition metal oxides, these phenomena are
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30 very rare. In most of the amorphous oxides or oxide glasses containing 3d transition metal
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32 and/or trivalent rare-earth ions, antiferromagnetic rather than ferromagnetic interaction is
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34 predominant among the magnetic ions.³⁷⁻⁴⁶ Furthermore, it is usual that the magnetic transition
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36 temperature is decreased by one order of magnitude when crystalline oxides are made to be
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38 amorphous with the composition kept constant. For instance, whereas crystalline $\alpha\text{-Fe}_2\text{O}_3$ is
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40 known to show weak ferromagnetism below 950 K, amorphous Fe_2O_3 manifests a cluster spin
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42 glass transition at 35.1 ± 0.1 K.⁴⁰ Also, amorphous BiFeO_3 shows a spin glass transition at 20
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44 K³⁹ while crystalline BiFeO_3 is antiferromagnetic with Néel temperature of 643 K.⁴⁷ The
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46 ferromagnetic interaction observed even in an amorphous oxide is characteristic of the Eu^{2+} ion,
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48 as positive Weiss temperature was observed for some oxide glasses containing a large amount
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6 of Eu^{2+} ions.^{48,49} The ferromagnetic phase transition was also observed for aluminoborosilicate
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8 glass containing 60.0 mol% of EuO , although the Curie temperature is as low as 2.2 K.⁴⁹
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11 Figure 9 depicts the magnetic field dependence of magnetization measured at 2.0 K for
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13 the amorphous EuTiO_3 and Eu_2TiO_4 thin films. In this figure, the theoretical magnetization
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15 curve calculated by using the Brillouin function for paramagnetic Eu^{2+} ion at 2.0 K is also
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17 shown. The slope of the magnetization curve at low magnetic fields is steeper for the
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19 amorphous EuTiO_3 and Eu_2TiO_4 than for the Brillouin function. This fact suggests that the
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21 ferromagnetic interaction is dominant in the amorphous thin films. We can estimate the
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23 magnetic moment per Eu ion to be $7\mu_B$ from the saturation magnetization at high magnetic
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25 fields for both of the thin films. This value is coincident with the theoretical one for $4f^7$ state
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27 of Eu^{2+} , indicating that almost all the europium ions are present as a divalent state in the
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29 amorphous thin films.
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35 The reason why the ferromagnetic state is stabilized in the amorphous EuTiO_3 and
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37 Eu_2TiO_4 thin films can be understood in terms of the local structure of Eu^{2+} in the amorphous
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39 phases and the above-mentioned mechanism to bring about the ferromagnetic interaction among
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41 Eu^{2+} ions. Figures 10 (a) and (b) illustrate experimental EXAFS spectra (EXAFS oscillation
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43 curves $\chi(R)$ s as a function of radial distance) at Eu L_3 -edge (denoted by open squares) for the
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45 amorphous EuTiO_3 and Eu_2TiO_4 thin films, respectively. The insets depict the EXAFS
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47 oscillation curves in the q -space. The solid curves stand for the best-fits of theoretical ones to
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49 the first Eu–O coordination peaks. Structural parameters evaluated from the analysis, i.e., the
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51 average coordination number of Eu^{2+} , $n_{\text{Eu}^{2+}}$, and the nearest Eu–O bond length, $d_{\text{Eu-O}}$, are listed
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53 in Table 3. For crystalline EuTiO_3 , $n_{\text{Eu}^{2+}}=12$ and $d_{\text{Eu-O}}=0.275$ nm, and for crystalline Eu_2TiO_4 ,
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6 the structure of which is K_2NiF_4 -type, $n_{Eu^{2+}}=9$ and $d_{Eu-O}=0.270$ nm (an averaged value).¹⁹
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8 Hence, both the coordination number of Eu^{2+} and the Eu-O bond length are much smaller for
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10 the amorphous $EuTiO_3$ and Eu_2TiO_4 than for their crystalline counterparts. The coordination
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12 number and the Eu-O bond strength in the amorphous phases are rather similar to those of
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14 crystalline EuO with rock salt-type structure, for which $n_{Eu^{2+}}=6$ and $d_{Eu-O}=0.257$ nm.¹⁸ The
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16 result of the structural analysis on the EXAFS spectra discloses the origin of the ferromagnetic
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18 interaction stronger in the amorphous thin films than in their crystalline counterparts. The
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20 indirect exchange interaction illustrated in Fig.6 is proportional to $J_{intra}b^2/U_{fd}^2$, where J_{intra} is the
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22 intra-atomic exchange coupling constant between the 4f and 5d levels of Eu^{2+} , b is the transfer
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24 integral between the nearest-neighboring Eu^{2+} ions, and U_{fd} is the difference in energy between
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26 the 4f and 5d levels. As readily seen from Fig. 6, U_{fd} becomes smaller as the crystal field
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28 splitting of 5d level is greater, leading to stronger ferromagnetic interactions.¹⁹ For instance,
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30 the crystal field is much stronger in crystalline EuO than in crystalline $EuTiO_3$ because the
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32 coordination number of Eu^{2+} is 6 in the former and 12 in the latter. Subsequently, the
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34 ferromagnetic interaction among Eu^{2+} ions is so strong that Curie temperature as high as 77 K is
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36 observed in crystalline EuO,⁵⁰ while antiferromagnetic transition takes place at rather low
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38 temperature like 5.3 K in crystalline $EuTiO_3$. Since the coordination number of Eu^{2+} and Eu-O
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40 bond length in the amorphous $EuTiO_3$ and Eu_2TiO_4 are rather close to those in crystalline EuO
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42 as demonstrated by the EXAFS spectra, the crystal field splitting of 5d level is larger in the
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44 amorphous $EuTiO_3$ and Eu_2TiO_4 than in their crystalline counterparts, resulting in the
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46 enhancement of ferromagnetic interaction in the amorphous phases.
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56 The stabilization of ferromagnetic state by the amorphization was also observed in
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EuZrO₃.⁵¹ Crystalline EuZrO₃ is an antiferromagnet with the Néel temperature of 4.1K,²² whereas amorphous EuZrO₃ thin film prepared by the PLD method shows ferromagnetic transition at 8 K.⁵¹ It should be noted that the magnetic transition temperature is higher for the amorphous phase than for its crystalline counterpart. The mechanism based on the indirect exchange interaction leads to the ferromagnetic configuration of magnetic moments of Eu²⁺ ions in the amorphous EuZrO₃ similarly to the amorphous EuTiO₃ and Eu₂TiO₄.

IV. CONCLUSIONS

We have synthesized single-crystalline EuTiO₃ thin films on different kinds of substrate, i.e., LaAlO₃, SrTiO₃, and DyScO₃ by using a PLD method so that the strain induced at the interface between the thin film and the substrate due to lattice mismatch leads to a change in lattice volume of the EuTiO₃ thin film, and examined the effect of strain on magnetic properties of the resultant EuTiO₃ thin films. All the as-deposited EuTiO₃ thin films manifest elongation of lattice by about 2 % in a direction perpendicular to the surface of the thin films, whereas the in-plane lattice constant of the thin films is determined by the lattice mismatch, so that the contraction and elongation of the lattice in a direction parallel to the surface of the EuTiO₃ thin film are observed for LaAlO₃ and DyScO₃ substrates, respectively. Subsequently, the lattice volume of the EuTiO₃ thin film increases in the order that DyScO₃ > SrTiO₃ > LaAlO₃. The temperature and magnetic field dependence of magnetization indicates that all the EuTiO₃ thin films exhibit ferromagnetic transition at low temperatures. Besides, the magnetization at low temperatures monotonically increases in the order that DyScO₃ > SrTiO₃ > LaAlO₃; namely, the magnetization at low temperatures increases with an increase in lattice volume for the

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6 as-deposited EuTiO_3 thin film. The result is qualitatively coincident with the calculations
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8 based on hybrid Hartree-Fock density functional approach that the exchange coupling constant
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10 J_1 increases and changes its sign from negative to positive as the lattice volume of EuTiO_3 is
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12 increased. The amorphous phase of EuTiO_3 and Eu_2TiO_4 synthesized by the PLD method as a
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14 thin film form on SiO_2 substrate is also ferromagnetic when the temperature is decreased. It is
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16 interesting that amorphous EuTiO_3 is ferromagnetic although the crystalline counterpart is
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18 antiferromagnetic; it is a very rare case that amorphization makes an antiferromagnetic
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20 compound ferromagnetic. Furthermore, the magnetic transition temperature of amorphous
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22 phase is compared to or higher than that of the crystalline counterpart for EuTiO_3 and Eu_2TiO_4 ,
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24 respectively. The larger ferromagnetic interaction in the amorphous phases can be explained in
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26 terms of the local structure of Eu^{2+} similar to the chemical environment around Eu^{2+} in
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28 ferromagnetic crystal EuO . It is concluded that the indirect exchange interaction via 5d state
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30 of Eu^{2+} overcomes the superexchange interaction via Ti^{4+} 3d state in the magnetic interaction
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32 among the Eu^{2+} ions, leading to not only the strain-induced ferromagnetism observed for
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34 EuTiO_3 but also the ferromagnetism caused by amorphization for EuTiO_3 and Eu_2TiO_4 .
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6 Table 1 Molar ratio of Eu to Ti in the as-deposited europium titanate thin films grown on
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8 different sorts of substrate. The molar ratio is almost equal to 1 in all the thin films, suggesting
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10 that stoichiometric EuTiO_3 was synthesized.
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Substrate	Molar ratio of Eu to Ti in the europium titanate thin films
LaAlO_3	1.02
SrTiO_3	0.98
DyScO_3	1.02

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Table 2 Variation in lattice constant and lattice volume for EuTiO_3 thin films grown on LaAlO_3 , SrTiO_3 , and DyScO_3 substrates. A relative difference in the values between the thin film and bulk EuTiO_3 is listed. Δl_1 and Δl_2 denote the change in lattice constant in a direction parallel and perpendicular to the surface of the thin film, respectively. ΔV stands for the change in lattice volume relative to the bulk EuTiO_3 .

Substrate	Δl_1 (%)	Δl_2 (%)	ΔV (%)
LaAlO_3	-0.5	+1.89	+1.56
SrTiO_3	0.0	+2.41	+2.41
DyScO_3	+1.05	+1.77	+3.92

Table 3 Structural parameters obtained from EXAFS for Eu^{2+} in amorphous EuTiO_3 (a-ETO) and Eu_2TiO_4 (a-2ETO) thin films. $n_{\text{Eu}^{2+}}$ and $d_{\text{Eu-O}}$ denote the average coordination number of Eu^{2+} and the nearest-neighboring Eu–O bond length, respectively.

Compound	$n_{\text{Eu}^{2+}}$	$d_{\text{Eu-O}}$ (nm)
amorphous EuTiO_3	6.4	0.2480
amorphous Eu_2TiO_4	6.3	0.2472

Figure captions

Fig. 1 AFM images of EuTiO_3 thin films grown on (a) LaAlO_3 , (b) SrTiO_3 , and (c) DyScO_3 substrates. LAO, STO, and DSO denote LaAlO_3 , SrTiO_3 , and DyScO_3 , respectively.

Fig. 2 Reciprocal space mappings for EuTiO_3 thin films as well as LaAlO_3 , SrTiO_3 , and DyScO_3 substrates. Q_x and Q_y correspond to the reciprocal lattice vectors parallel and perpendicular to the surface of the EuTiO_3 thin film, respectively. The small circle shown in each of the mappings denotes the reciprocal lattice of bulk EuTiO_3 .

Fig. 3 Dependence of magnetization on temperature for EuTiO_3 thin films grown on LaAlO_3 (diamond), SrTiO_3 (circle), and DyScO_3 (square) substrates as well as for bulk EuTiO_3 (triangle). The inset is a magnified view for bulk EuTiO_3 .

Fig. 4 Dependence of magnetization on magnetic field at 2 K for EuTiO_3 thin films grown on LaAlO_3 (diamond), SrTiO_3 (circle), and DyScO_3 (square) substrates as well as for bulk EuTiO_3 (triangle). The insets depict the magnetization at low magnetic fields for EuTiO_3 thin film grown on SrTiO_3 substrate (right inset: circle) and for bulk EuTiO_3 (left inset: triangle).

Fig. 5 Magnetic configurations and magnetic interactions in EuTiO_3 lattice. A, F, and G denote A-type antiferromagnetic, ferromagnetic, and G-type antiferromagnetic states, respectively. J_1 and J_2 stand for the exchange coupling constant between nearest-neighboring

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6 and next-nearest-neighboring Eu^{2+} ions, respectively.
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11 Fig. 6 Mechanism of indirect exchange interaction between Eu^{2+} ions to lead to ferromagnetic
12 state. 4f spins interact ferromagnetically with each other via 5d state.
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18 Fig. 7 (a) X-ray diffraction patterns for amorphous EuTiO_3 (a-ETO) and Eu_2TiO_4 (a-2ETO) thin
19 films. (b) high-resolution transmission electron micrograph and selected area electron
20 diffraction pattern for amorphous EuTiO_3 .
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27 Fig. 8 Dependence of magnetization on temperature at a applied dc magnetic field of 100 Oe
28 for amorphous EuTiO_3 (a-ETO) and Eu_2TiO_4 (a-2ETO) thin films. The arrows indicate an
29 inflection point in each of the magnetization curves. The Curie temperature is defined as the
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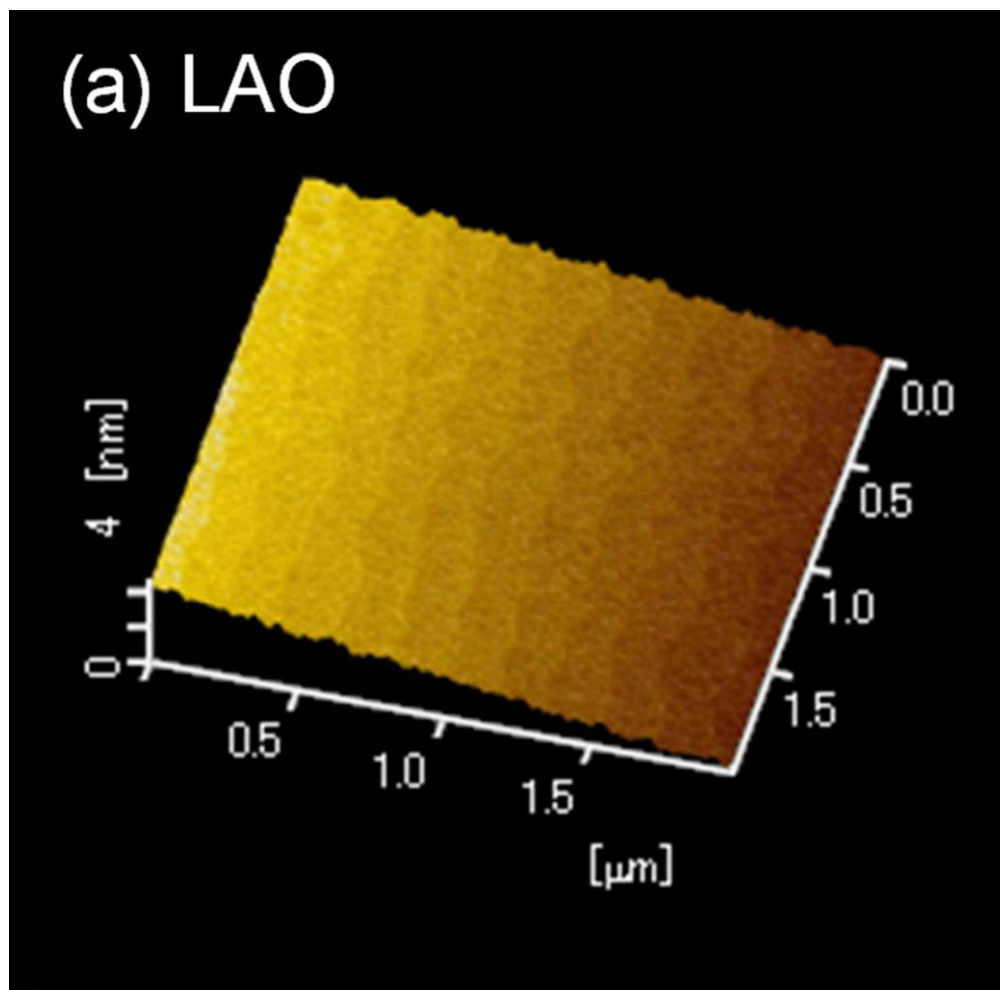
40 Fig. 9 Dependence of magnetization on magnetic field at 2.0 K for amorphous EuTiO_3
41 (a-ETO) and Eu_2TiO_4 (a-2ETO) thin films. The solid curve represents the theoretical one
42 calculated using the Brillouin function for paramagnetic Eu^{2+} ions at 2.0 K
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49 Fig. 10 Eu L_3 -edge EXAFS spectra in R-space (open squares) and theoretical curves (solid
50 lines) fitted to the first-shell components of the experimental data for (a) EuTiO_3 (a-ETO) and
51 (b) Eu_2TiO_4 (a-2ETO) thin films. R is the radial distance from Eu and $\chi(R)$ is the EXAFS
52 oscillation curve. The insets illustrate a comparison of the real part of Fourier filtered
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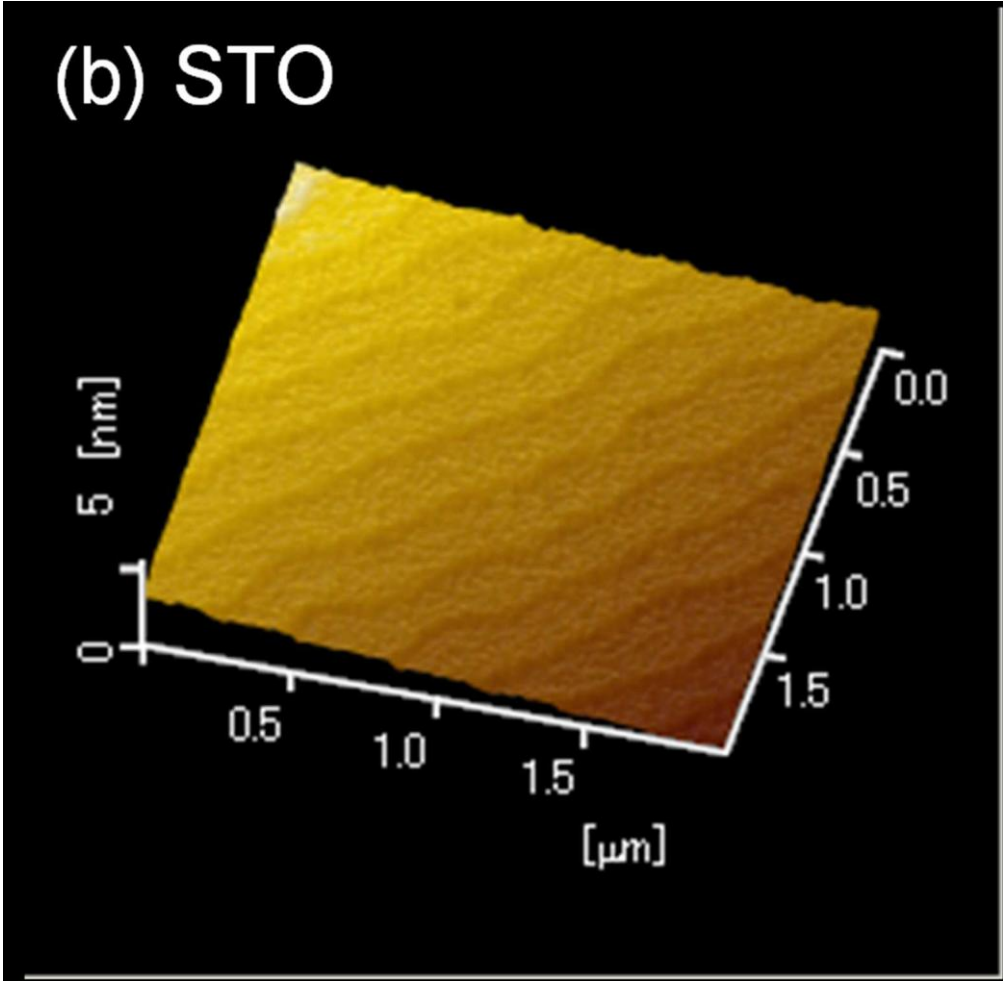
first-shell signals in q-space (open squares) and the theoretical curves (sold lines).

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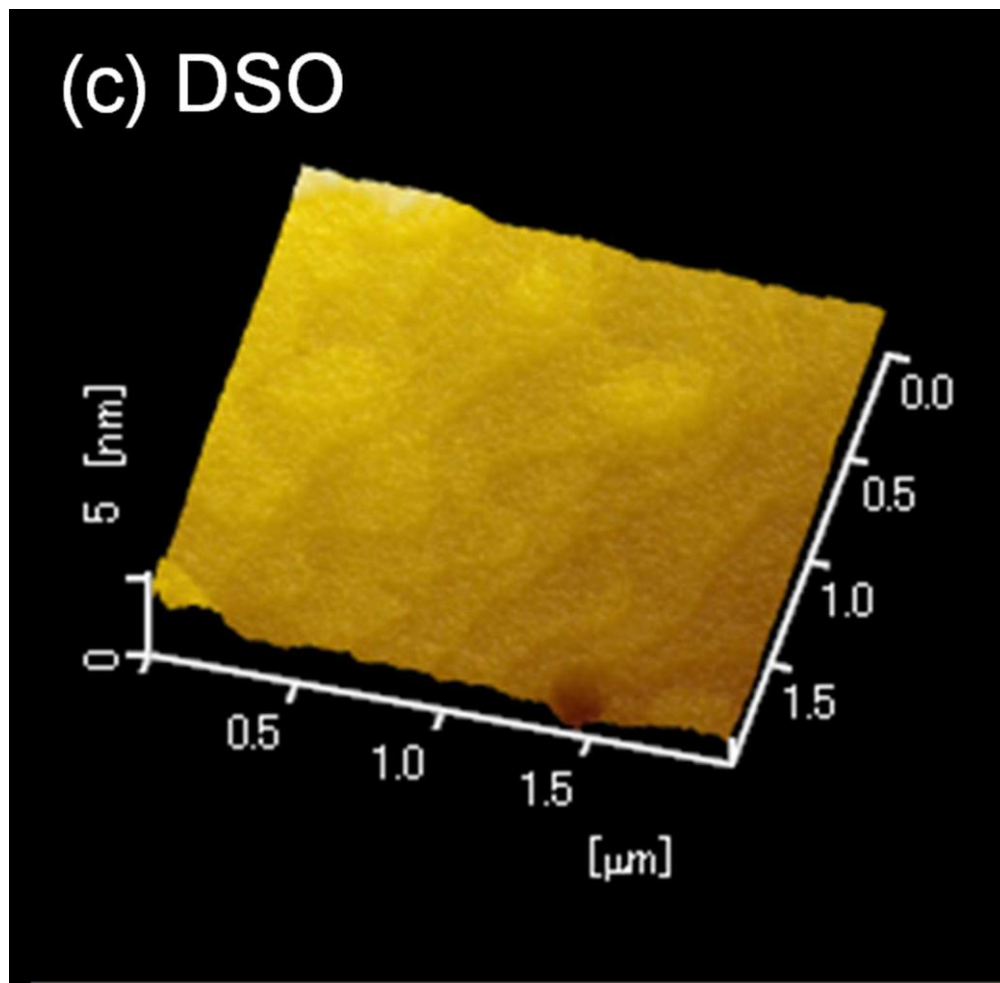


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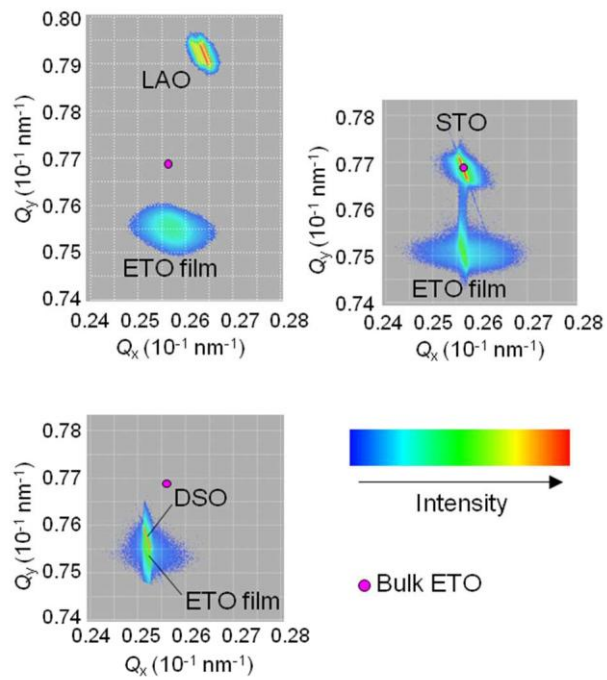
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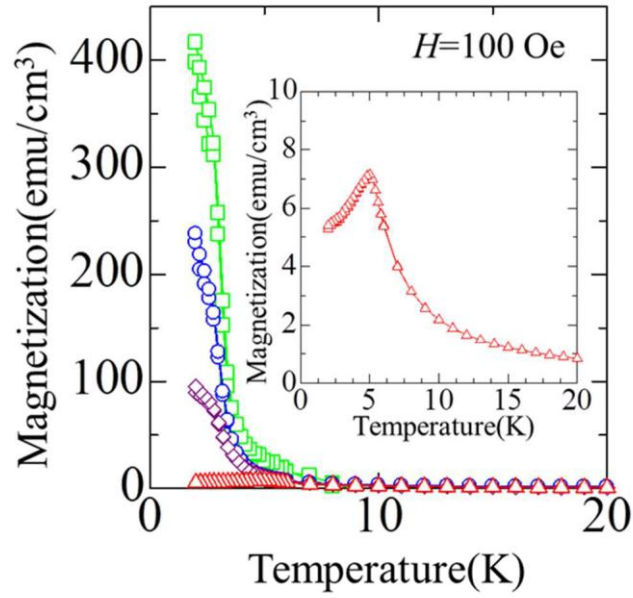
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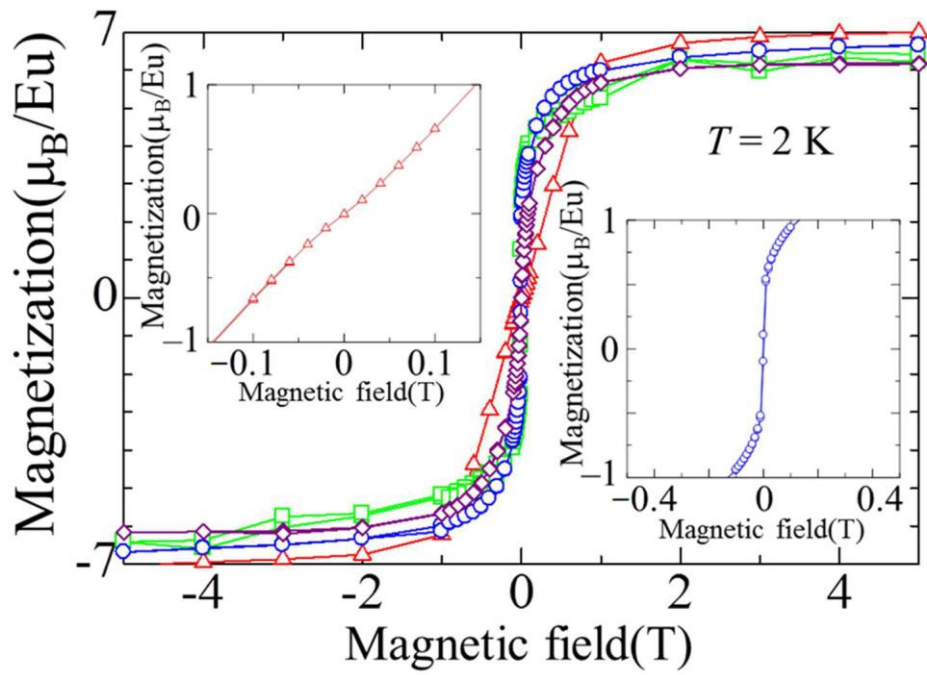
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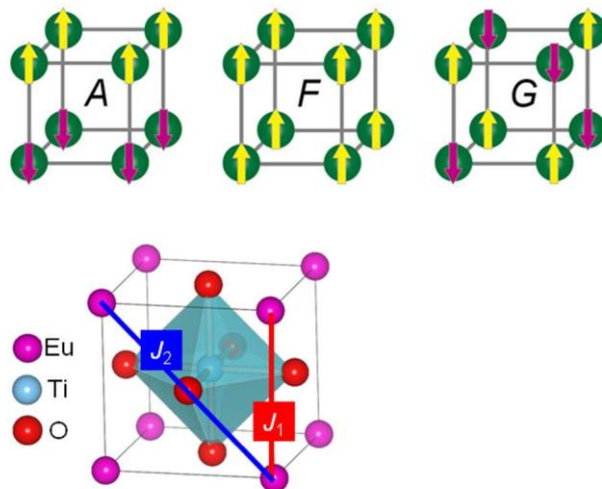
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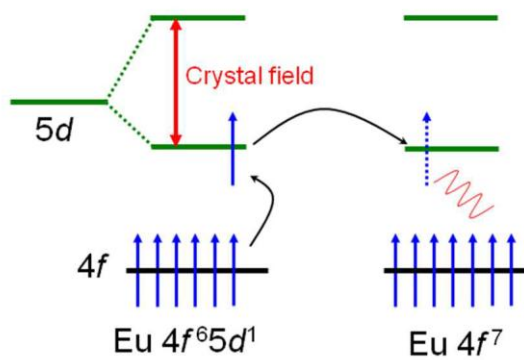
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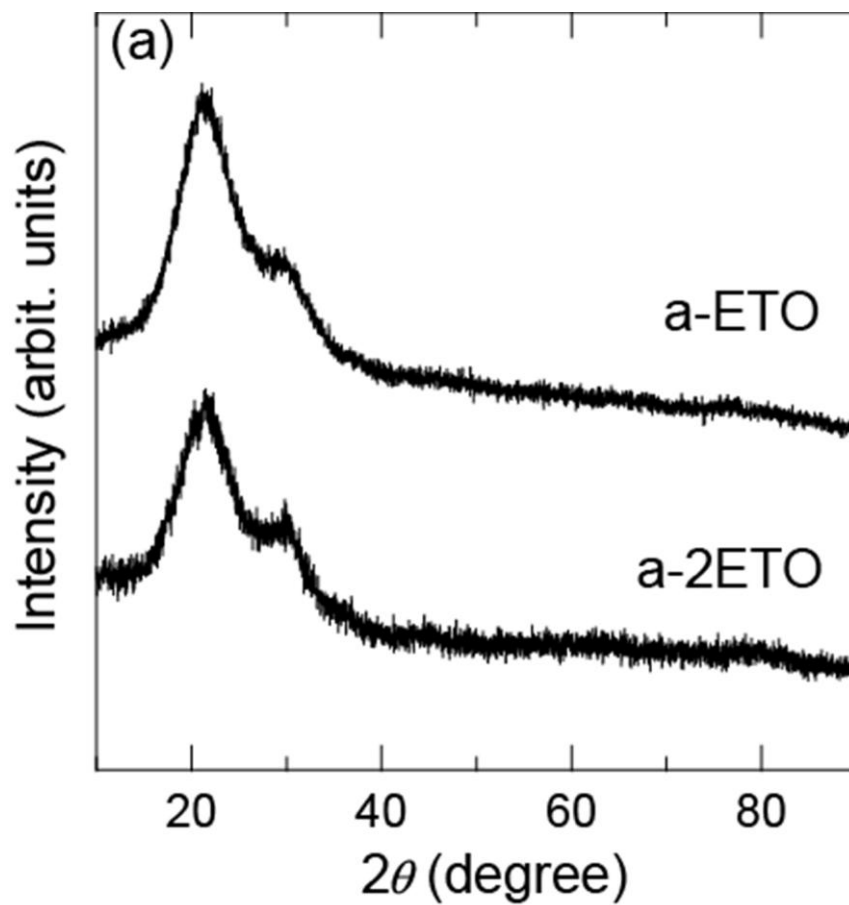
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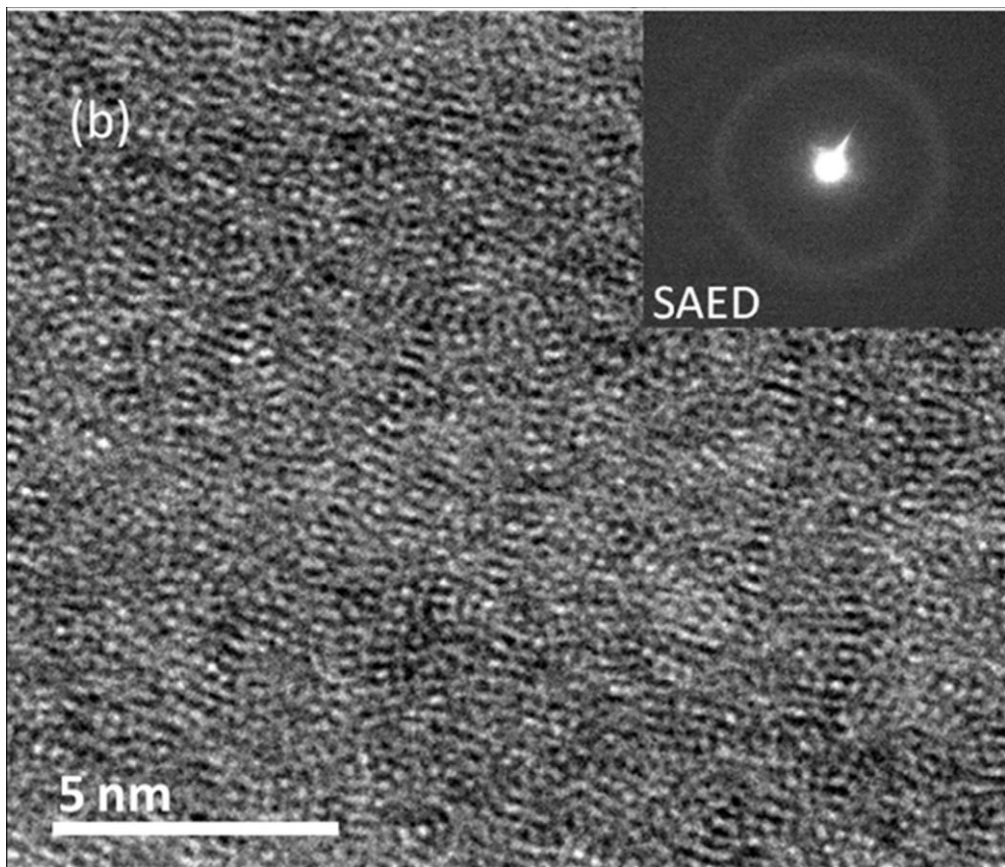
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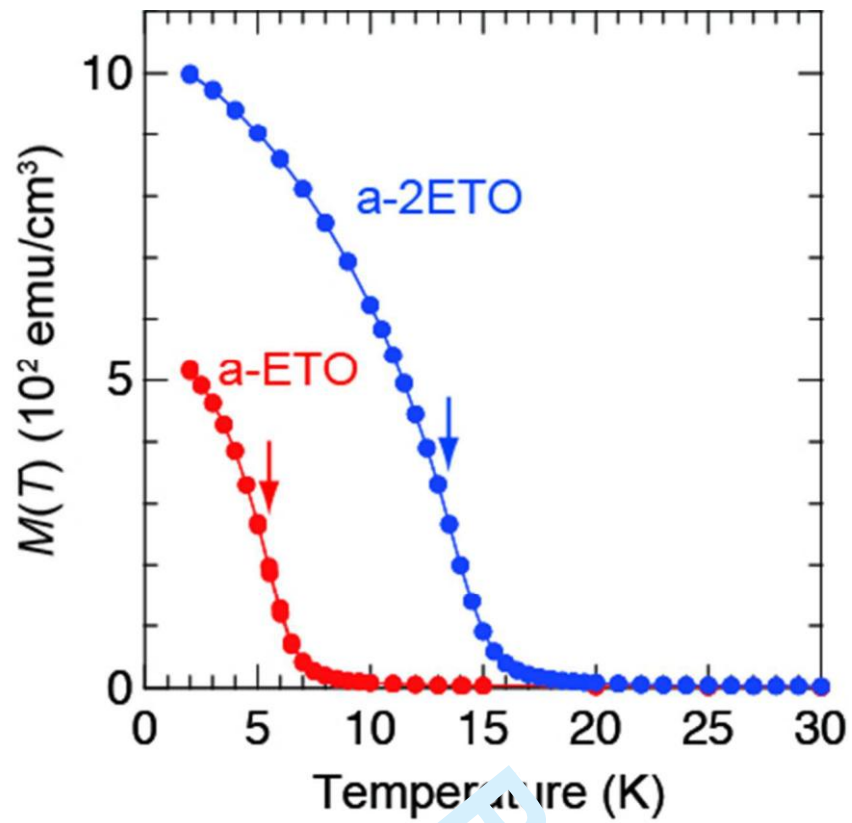


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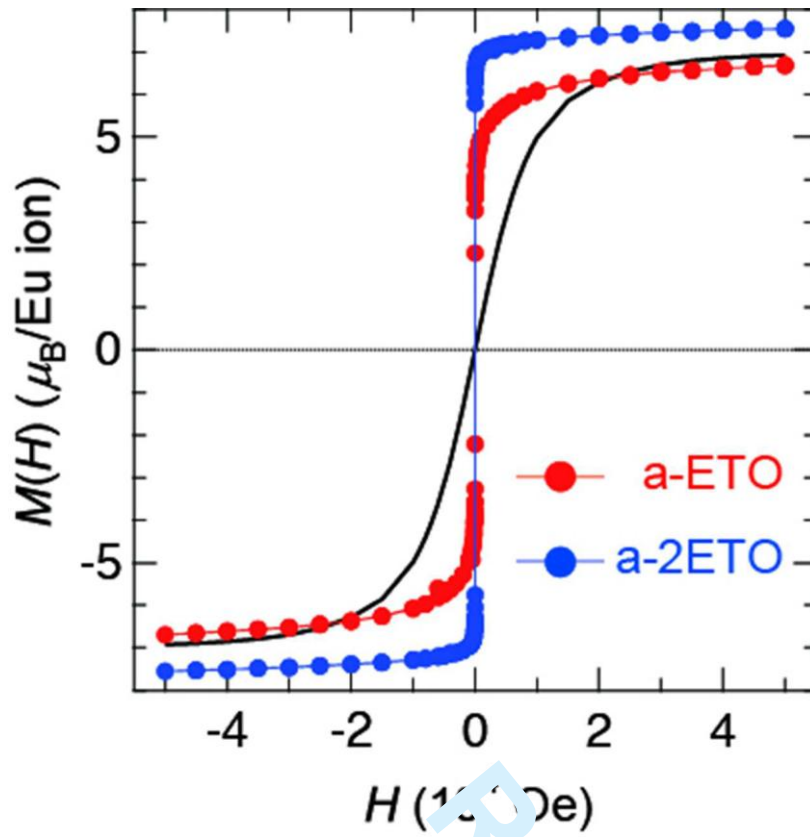
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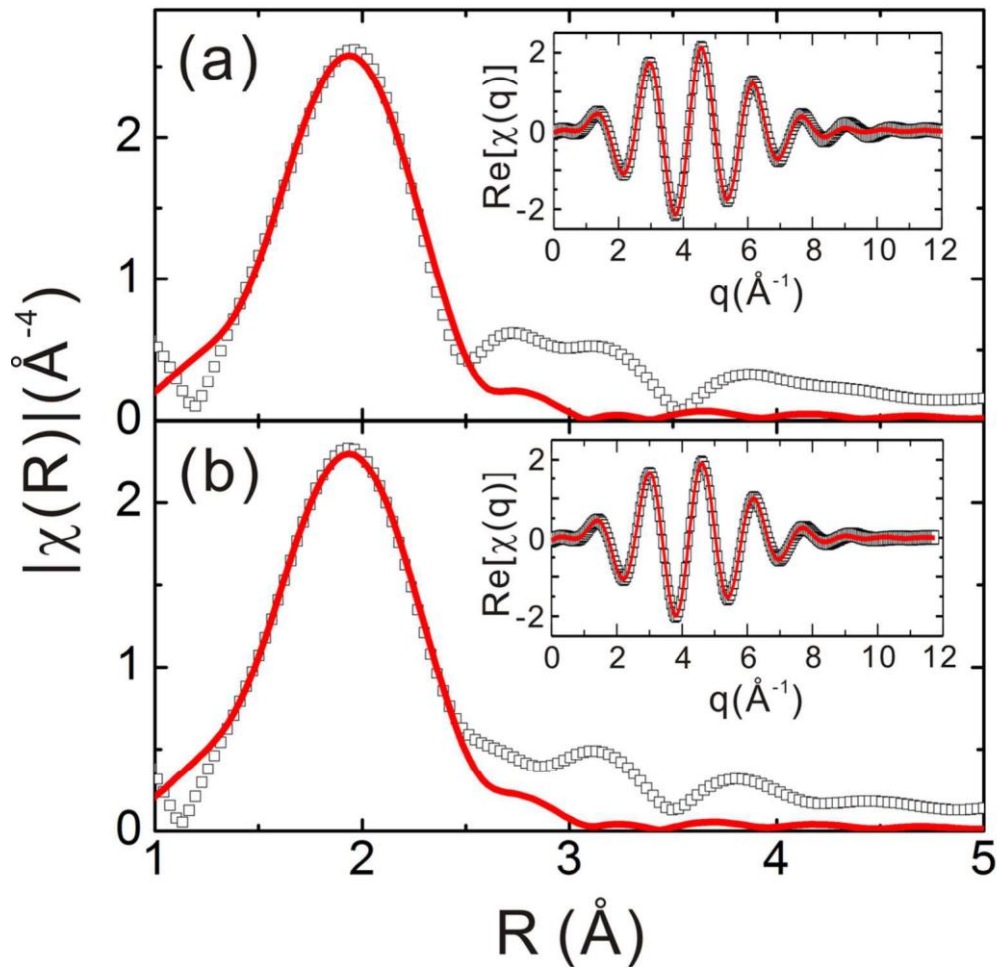


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